

# MOS MEMORIES

PRODUCT	DESCRIPTION	MIL TEMP + BURN-IN	NFC 96883	MIL STD 883	CECC 90000
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## EPROM'S

<b>ET2716</b>	2 K×8	NMOS (450 ns)	■	■		
<b>ETC2716</b>	2 K×8	CMOS (450 ns)	■	■		
<b>ETC2732</b>	4 K×8	CMOS (450 ns)	■	■		
<b>27C64</b>	8 K×8	CMOS (250 ns)	■	■	■	□
<b>27C256</b>	32 K×8	CMOS (150, 200, 250 ns)	■	■	□	□
<b>27C1024</b>	64 K×8	CMOS (150 ns)	□		□	□
<b>27C1001</b>	128 K×8	CMOS (150 ns)	□		□	□
<b>27C2001</b>	256 K×8	CMOS (150 ns)	□		□	□
<b>27C4001</b>	512 K×8	CMOS (100 ns)	□		□	□
<b>27C4002</b>	256 K×16	CMOS (100 ns)	□		□	□

Above products are available in CERDIP with and without window, LCCC with and without window package.

■ Available.      □ To be introduced.